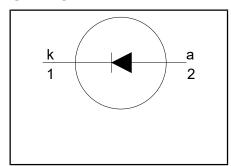
Damper diode fast, high-voltage

BY329X-1500, BY329X-1500S

FEATURES

- Low forward volt drop
- · Fast switching
- Soft recovery characteristic
- High thermal cycling performance
 Isolated mounting tab

SYMBOL



QUICK REFERENCE DATA

$$V_R = 1500 \text{ V}$$
 $V_F \le 1.35 \text{ V} / 1.5 \text{ V}$
 $I_{F(peak)} = 6 \text{ A (f = 16 kHz)}$
 $I_{F(peak)} = 6 \text{ A (f = 70 kHz)}$
 $I_{FSM} \le 75 \text{ A}$
 $t_{rr} \le 230 \text{ ns} / 160 \text{ ns}$

GENERAL DESCRIPTION

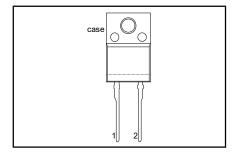
Glass-passivated double diffused rectifier diode featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The device is intended for use in TV receivers and PC monitors.

The BY329X series is supplied in the conventional leaded SOD113 package.

PINNING

PIN	DESCRIPTION	
1	anode	
2	cathode	
tab	isolated	

SOD113



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V_{RSM}	Peak non-repetitive reverse voltage		-	1500		V
V_{RRM}	Peak repetitive reverse voltage		-	1500		V
V_{RWM}	Crest working reverse voltage		-	130	00	V
I _{F(peak)}	Peak working forward current	BY329X f = 16 kHz f = 70 kHz	- -	- 1500 6 -	-1500S - 6	A A
I _{FRM}	Peak repetitive forward current	$t = 25 \mu s$; $δ = 0.5$; $T_{hs} \le 86 °C$	-	14		Α
I _{F(RMS)} I _{FSM}	RMS forward current Peak non-repetitive forward current	t = 10 ms sinusoidal; T _j = 150 °C prior to surge; with reapplied V _{RWM(max)}	- -	11 75		A A
${\mathsf T}_{stg} \atop {\mathsf T}_{\mathsf j}$	Storage temperature Operating junction temperature	surge; with reapplied V _{RWM(max)}	-40 -	150 150		Ç

Philips Semiconductors Product specification

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ISOLATION LIMITING VALUE & CHARACTERISTIC

T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	-		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-hs}$ $R_{th j-a}$	Thermal resistance junction to heatsink Thermal resistance junction to ambient	with heatsink compound without heatsink compound in free air.		- - 55	4.8 5.9 -	K/W K/W K/W

STATIC CHARACTERISTICS

 T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	TY	Έ.	M	AX.	UNIT
		BY329X-	1500	1500S	1500	1500S	
V _F	Forward voltage	I _F = 6.5 A I _F = 6.5 A; T _i = 125 °C	1.1 1.05	1.3 1.2	1.45 1.35	1.6 1.5	V
I _R	Reverse current	$\dot{V}_R = 1300 \text{ V}$ $V_R = 1300 \text{ V}$; $T_j = 125 ^{\circ}\text{C}$	1 1	250 1	1 1	250 1	μA mA

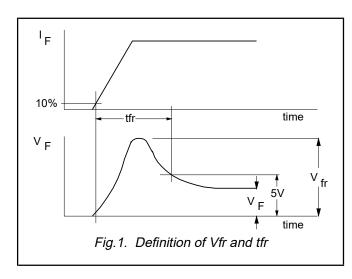
DYNAMIC CHARACTERISTICS

T_i = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	T	/P.	M	AX.	UNIT
		BY329X	1500	1500S	1500	1500S	
t _{rr}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ $dI_F/dt = 50\text{A}/\mu\text{s}$	0.18	0.13	0.23	0.16	μs
$egin{array}{c} Q_s \ V_{fr} \ t_{fr} \end{array}$	Reverse recovery charge Peak forward recovery voltage Forward recovery time	$I_F = 2 \text{ A}; -dI_F/dt = 20 \text{ A}/\mu\text{s}$ $I_F = 6.5 \text{A}; dI_F/dt = 50 \text{A}/\mu\text{s}$ $I_F = 6.5 \text{A}; dI_F/dt = 50 \text{A}/\mu\text{s}$	1.6 17 210	0.7 23 220	2.0 30 300	0.95 40 320	μC V ns

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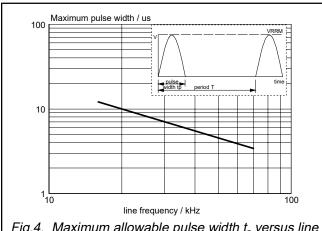
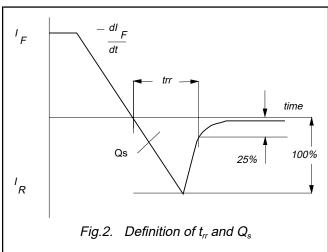
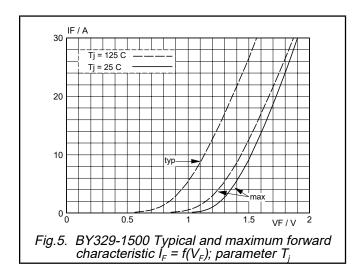
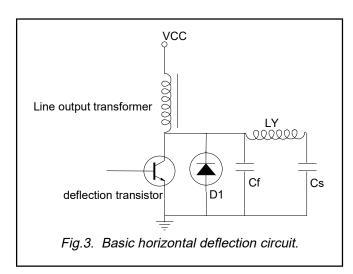


Fig.4. Maximum allowable pulse width t_p versus line frequency; Basic horizontal deflection circuit.







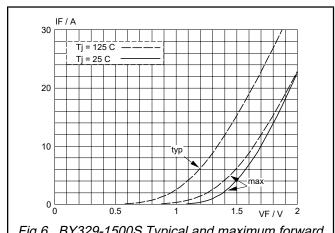
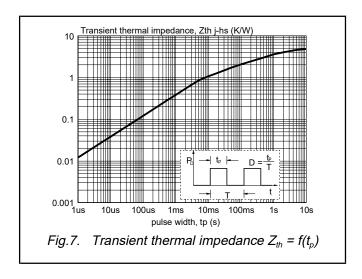


Fig.6. BY329-1500S Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

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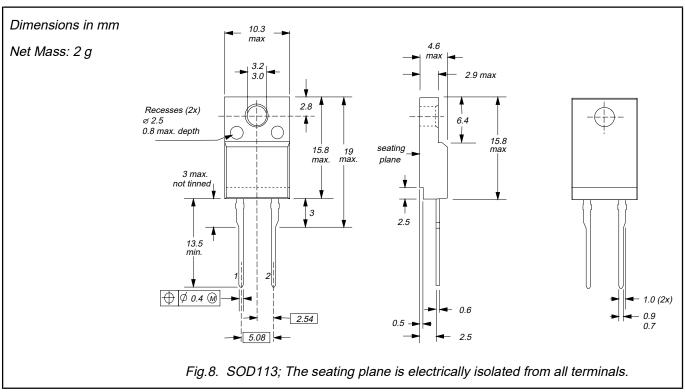
BY329X-1500, BY329X-1500S



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BY329X-1500, BY329X-1500S

MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

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DEFINITIONS

Data sheet status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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